# Photointerrupter, General type

## Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limits	Unit
Input (LED)	Forward current	lF	50	mA
	Reverse voltage	VR	5	V
	Power dissipation	P□	80	mW
Output (photo- (transistor)	Collector-emitter voltage	Vceo	30	V
	Emitter-collector voltage	Veco	4.5	V
	Collector current	Ic	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25 to +85	°C
	Storage temperature	Tstg	-40 to +85	°C
	Soldering temperture	Tsol	260/3 *	°C/sec

<sup>\* 1</sup>mm from the body bottom.

## Electrical and optical characteristics (Ta=25°C)

	Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage		VF	-	1.3	1.6	٧	I⊧=50mA
	Reverse current		lR	-	_	10	μΑ	V <sub>R</sub> =5V
Output charac- teristics	Dark current		ICEO	-	-	0.5	μΑ	Vce=10V
	Peak sensitivity wavelength		λρ	-	800	-	nm	-
Transfer characteristics	Collector current		Ic	0.5	-	-	mA	Vce=5V, Ir=20mA
	Collector-emitter saturation voltage		VCE(sat)	-	0.1	0.5	V	I <sub>F</sub> =20mA, I <sub>C</sub> =0.5mA
	Response time	Rise time	tr	-	10	-	μs	Vcc=5V, I <sub>F</sub> =20mA, R <sub>L</sub> =100Ω
		Fall time	tf	-	10	-	μs	
Infrared light emitter diode	Cut-off frequency		fc	-	1	-	MHz	I==50mA  * Non-coherent Infrared light emitting diode used.
	Peak light emitting wavelength		λР	-	950	-	nm	
Photo I transistor	Response time		tr•tf	-	10	-	μs	$\label{eq:Vcc=5V} V_{cc=5V,\ lc=1mA,\ R_L=100\Omega} $$ * This product is not designed to be protected against electromagnetic wave.$
	Maximum sensitivity wavelength		λР	_	800	-	nm	-

### Electrical and optical characteristics curves

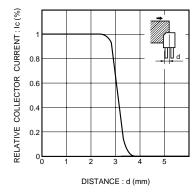


Fig.1 Relative output vs. distance (I)

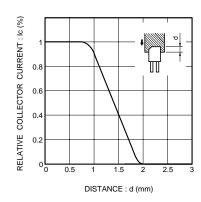


Fig.4 Relative output vs. distance (  $\rm II$  )

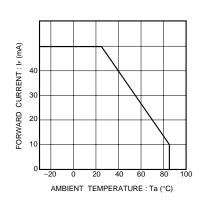


Fig.2 Forward current falloff

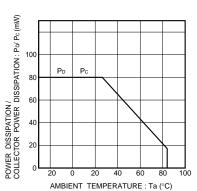
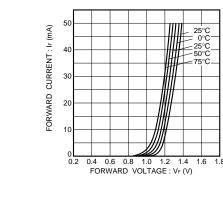


Fig.5 Power dissipation / collector power dissipation vs. ambient temperature Downloaded From Oneyac.com



Applications

Features

 $\label{fig.3} \textit{Forward current vs. forward voltage}$ 

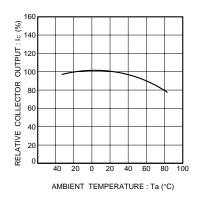
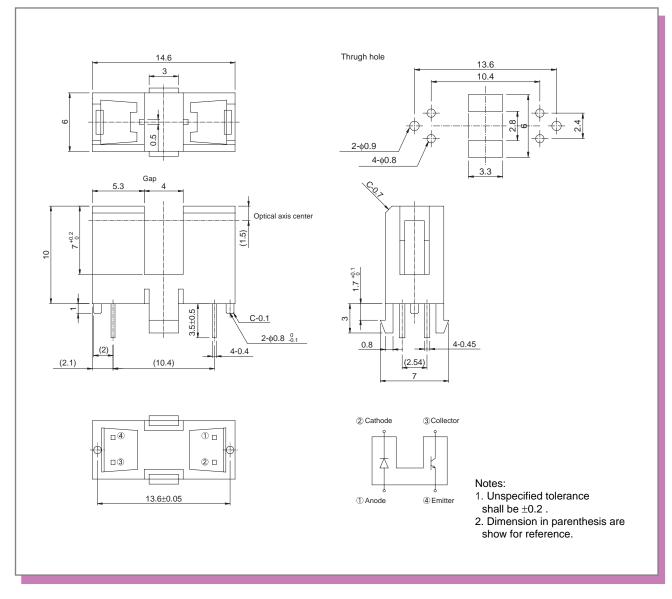


Fig.6 Relative output vs. ambient temperature

External dimensions (Unit : mm)



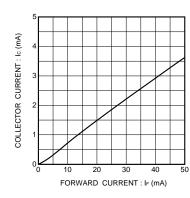


Fig.7 Collector current vs. forward current

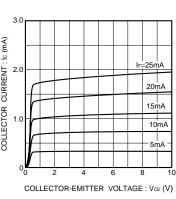


Fig.10 Output characteristics

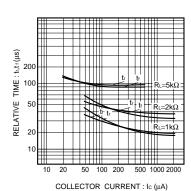


Fig.8 Response time vs. collector current

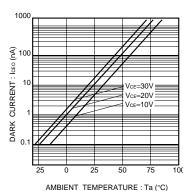
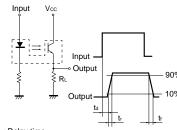


Fig.9 Dark current vs. ambient temperature



- t<sub>d</sub> : Delay time
- tr :Rise time (time for output current to rise from 10% to 90% of peak current)
- tr :Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time measurement circuit

#### **Notes**

- No technical content pages of this document may be reproduced in any form or transmitted by any
  means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
  otherwise dispose of the same, no express or implied right or license to practice or commercially
  exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

#### About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.



# 单击下面可查看定价,库存,交付和生命周期等信息

>>ROHM Semiconductor(罗姆)